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International IOR Rectifier

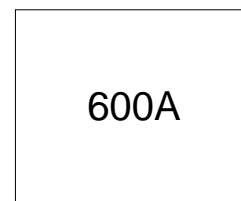
SD600N/R SERIES

STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

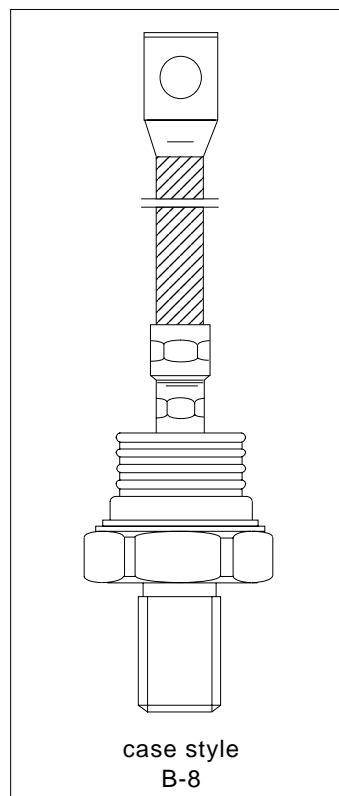


Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	SD600N/R		Units
	04 to 20	22 to 32	
$I_{F(AV)}$	600	600	A
@ T_C	92	54	°C
$I_{F(RMS)}$	940	940	A
I_{FSM} @ 50Hz	13000	10500	A
@ 60Hz	13600	11000	A
I^2t @ 50Hz	845	551	KA ² s
@ 60Hz	772	503	KA ² s
V_{RRM} range	400 to 2000	2200 to 3200	V
T_J	- 40 to 180	- 40 to 150	°C



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ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V _{RRM} , maximum repetitive peak reverse voltage V	V _{RSM} , maximum non-repetitive peak rev. voltage V	I _{RRM} max. @ T _J = T _J max. mA
SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	22	2200	2300	
	28	2800	2900	
	32	3200	3300	

Forward Conduction

Parameter	SD600N/R		Units	Conditions
	04 to 20	22 to 32		
I _{F(AV)} Max. average forward current @ Case temperature	600	600	A	180° conduction, half sine wave
	92	54	°C	
I _{F(AV)} Max. average forward current @ Case temperature	570	375	A	180° conduction, half sine wave
	100	100	°C	
I _{F(RMS)} Max. RMS forward current	940	940	A	DC @ T _C = 75°C (04 to 20), T _C = 36°C (25 to 32)
I _{FSM} Max. peak, one-cycle forward, non-repetitive surge current	13000	10500	A	t = 10ms No voltage reappplied
	13600	11000		t = 8.3ms reappplied
	10900	8830		t = 10ms 100% V _{RRM} reappplied
	11450	9250		t = 8.3ms reappplied
I ² t Maximum I ² t for fusing	845	551	KA ² s	t = 10ms No voltage reappplied
	772	503		t = 8.3ms reappplied
	598	390		t = 10ms 100% V _{RRM} reappplied
	546	356		t = 8.3ms reappplied
I ² √t Maximum I ² √t for fusing	8450	5510	KA ² √s	t = 0.1 to 10ms, no voltage reappplied
V _{F(TO)1} Low level value of threshold voltage	0.78	0.84	V	(16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J max.
V _{F(TO)2} High level value of threshold voltage	0.87	0.88		(I > π × I _{F(AV)}), T _J = T _J max.
r _{f1} Low level value of forward slope resistance	0.35	0.40	mΩ	(16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , T _J = T _J max.
r _{f2} High level value of forward slope resistance	0.31	0.38		(I > π × I _{F(AV)}), T _J = T _J max.
V _{FM} Max. forward voltage drop	1.31	1.44	V	I _{pk} = 1500A, T _J = T _J max, t _p = 10ms sinusoidal wave

Thermal and Mechanical Specifications

Parameter	SD600N/R		Units	Conditions
	04 to 20	22 to 32		
T _J Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T _{stg} Max. storage temperature range	-55 to 200	-55 to 200		
R _{thJC} Max. thermal resistance, junction to case	0.1		K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.04			Mounting surface, smooth, flat and greased
T Max. allowed mounting torque ±10%	50		Nm	Not lubricated threads
wt Approximate weight	454		g	
Case style	B-8			See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	T _J = T _J max.
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Ordering Information Table

Device Code

SD	60	0	N	32	P	C
①	②	③	④	⑤	⑥	⑦

- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)
- 6** - P = Stud base B-8 3/4" 16UNF-2A
- 7** - C = ceramic cap

NOTE: For Metric Device M24 x 1.5 Contact Factory

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Outlines Table

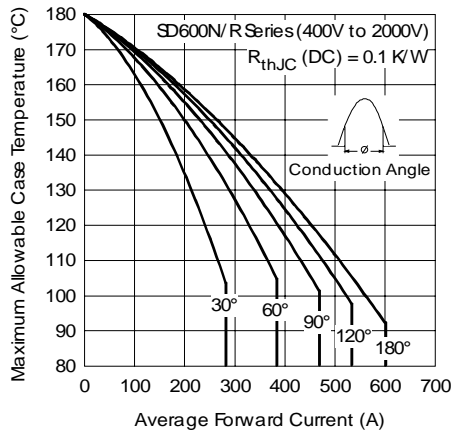
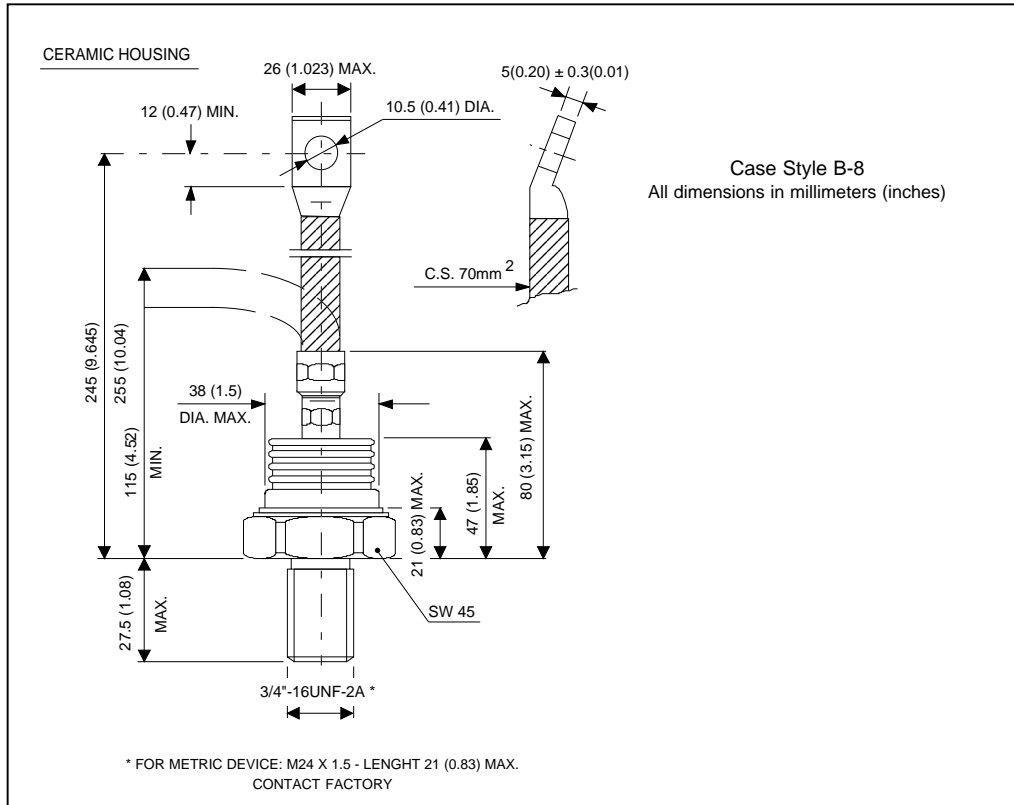


Fig. 1 - Current Ratings Characteristics

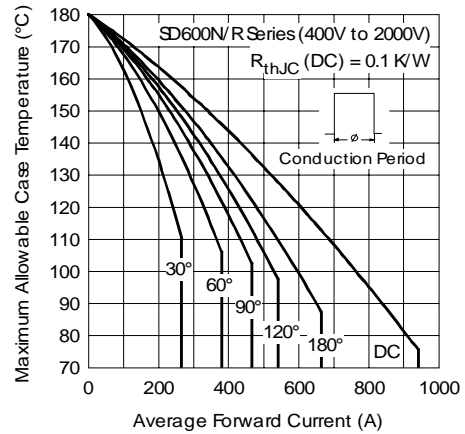


Fig. 2 - Current Ratings Characteristics

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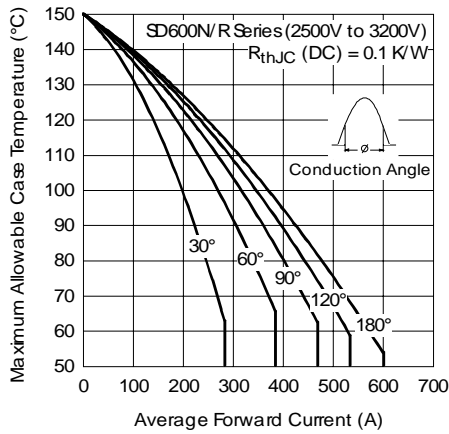


Fig. 3 - Current Ratings Characteristics

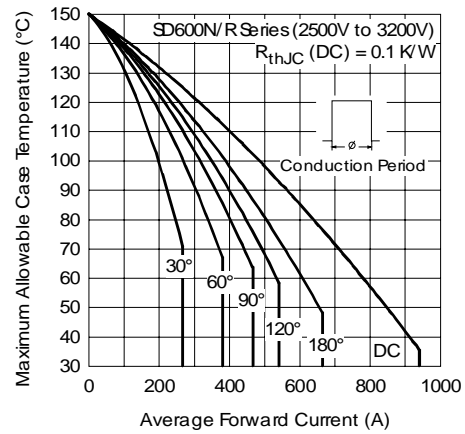


Fig. 4 - Current Ratings Characteristics

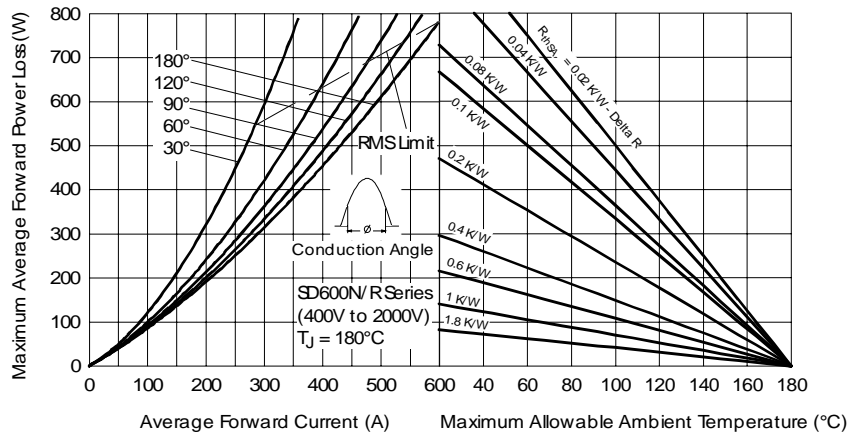


Fig. 5 - Forward Power Loss Characteristics

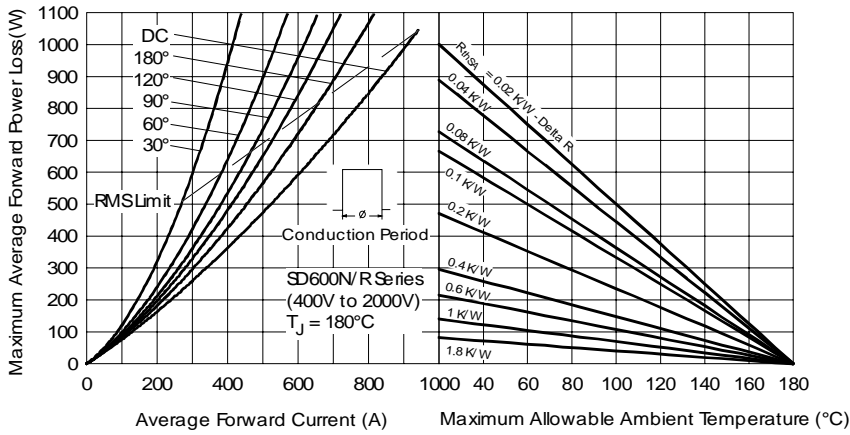


Fig. 6 - Forward Power Loss Characteristics

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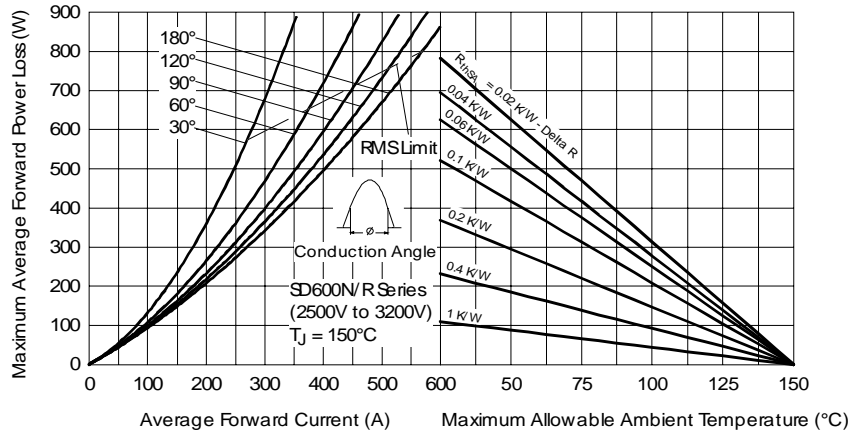


Fig. 7 - Forward Power Loss Characteristics

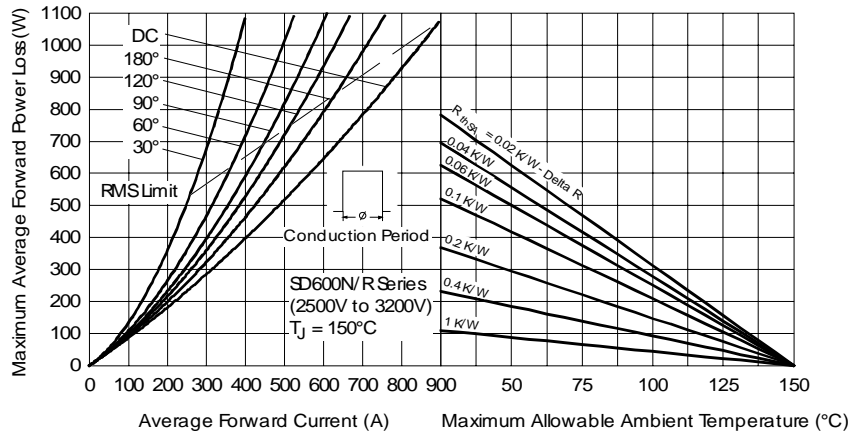


Fig. 8 - Forward Power Loss Characteristics

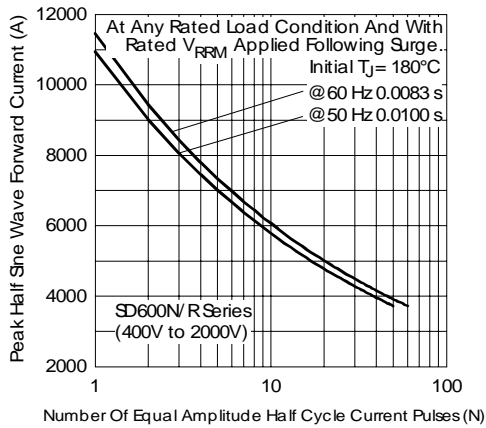


Fig. 9 - Maximum Non-Repetitive Surge Current

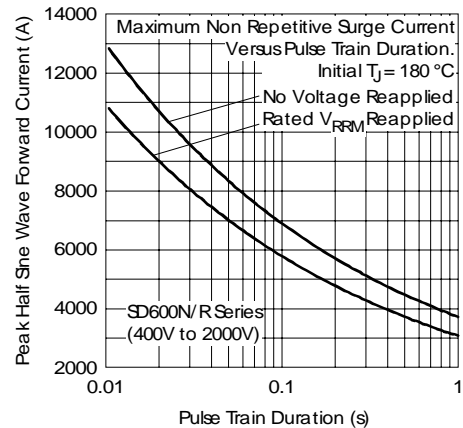


Fig. 10 - Maximum Non-Repetitive Surge Current

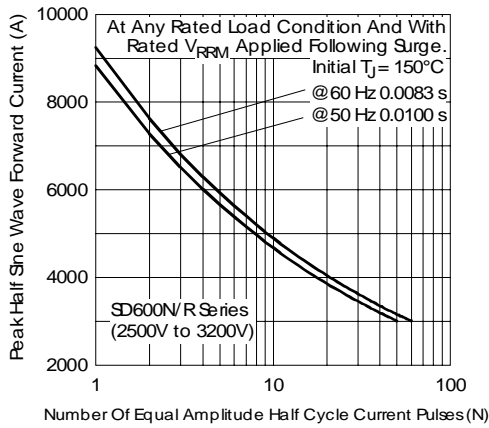


Fig. 11 - Maximum Non-Repetitive Surge Current

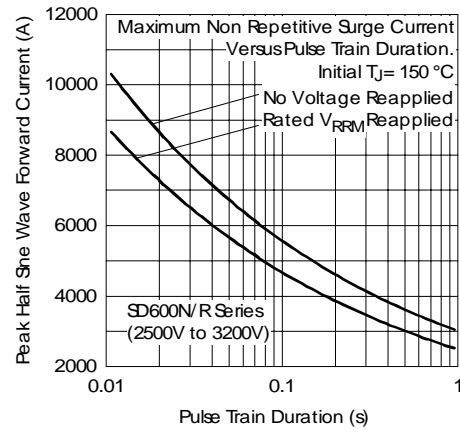


Fig. 12 - Maximum Non-Repetitive Surge Current

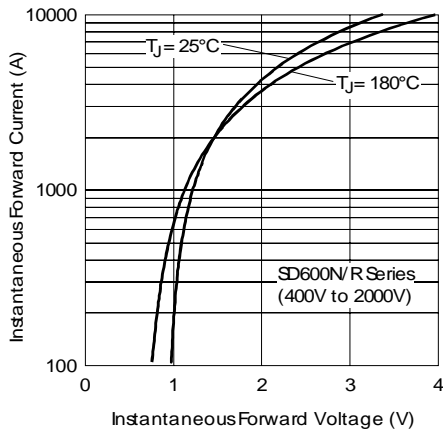


Fig. 13 - Forward Voltage Drop Characteristics

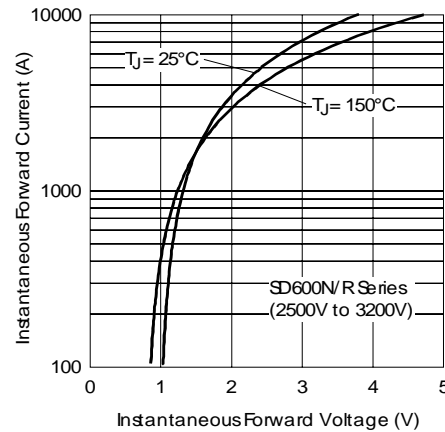


Fig. 14 - Forward Voltage Drop Characteristics

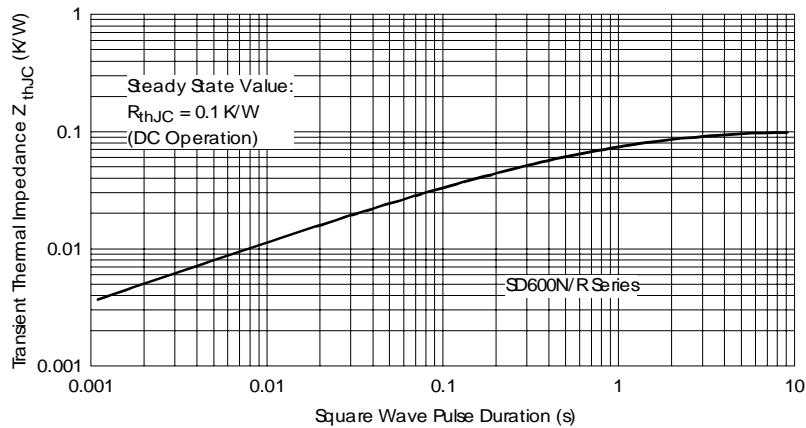


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics

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Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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